

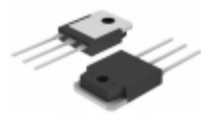



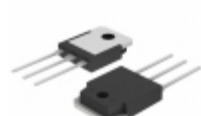


	<h2 style="color: red;">FQA11N90C_F109</h2>
	<p>Hersteller-Teilenummer: FQA11N90C_F109</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: FQA11N90C_F109 Fairchild/ON Semiconductor</p> <hr/> <p>Datenblätter:  FQA11N90C_F109.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 5540 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQA11N90C_F109
Hersteller	Fairchild/ON Semiconductor
Beschreibung	FQA11N90C_F109 Fairchild/ON Semiconductor
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5540 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3P
Verlustleistung (max)	300W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	900V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	11A (Tc)
Rds On (Max) @ Id, Vgs	1.1 Ohm @ 5.5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	80nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3290pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube



















































FQA11N90C_F109 ist neu im Original, Suche FQA11N90C_F109 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA11N90C_F109 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQA11N90C_F109: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQA11N90C FDK America MOSFET N-CH 900V 11A TO-3P</p>	 <p>FQA11N90_F109 Fairchild/ON Semiconductor FQA11N90_F109 Fairchild/ON Semiconductor</p>	 <p>FQA12N60 Fairchild/ON Semiconductor MOSFET N-CH 600V 12A TO-3P</p>	 <p>FQA11N90C Fairchild/ON Semiconductor MOSFET N-CH 900V 11A TO-3P</p>
 <p>FQA11N90-F109 AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 11.4A TO-3P</p>	 <p>FQA12P20 Fairchild/ON Semiconductor MOSFET P-CH 200V 12.6A TO-3P</p>	 <p>FQA12N60 AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 12A TO-3P</p>	 <p>FQA11N90C-F109 AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 11A TO-3P</p>

heiße Teile

Mehr

 FQA10N60C	 FQA10N60C	 FQA10N80C	 FQA10N80C	 FQA10N80C_F109
 FQA11N90	 FQA11N90	 FQA11N90C	 FQA11N90C	 FQA11N90C
 FQA11N90_F109	 FQA12N60C	 FQA12P20	 FQA12P20	 FQA13N50
 FQA13N50	 FQA13N50C	 FQA13N50C	 FQA13N50C_F109	 FQA13N80
 FQA13N80	 FQA13N80_F109	 FQA140N10	 FQA140N10	 FQA14N30
 FQA14N30	 FQA160N08	 FQA160N08	 FQA16N50	 FQA16N50
 FQA170N06	 FQA170N06	 FQA18N40	 FQA18N50	 FQA19N20C
 FQA19N20C	 FQA19N20L	 FQA19N20L	 FQA19N60	 FQA19N60
 FQA20N40	 FQA20N40	 FQA20N50	 FQA20N60	 FQA20N80
 FQA24N50	 FQA24N50	 FQA24N50F	 FQA24N50F	 FQA24N60

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